

## DARLINGTON COMPLEMENTARY SILICON POWER TRANSISTORS

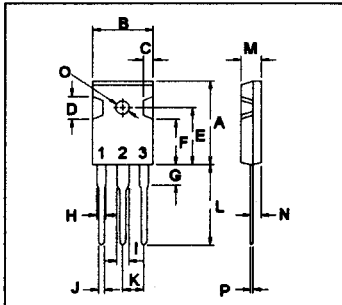
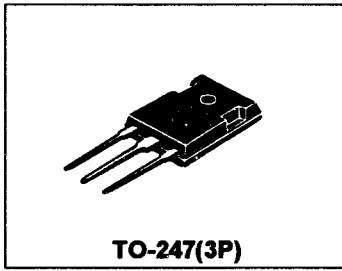
...designed for general-purpose amplifier and low speed switching applications

### FEATURES:

- \* Collector-Emitter Sustaining Voltage-  
 $V_{CEO(SUS)} = 60 \text{ V (Min) - TIP140, TIP145}$   
 $= 80 \text{ V (Min) - TIP141, TIP146}$   
 $= 100 \text{ V (Min) - TIP142, TIP147}$
- \* Collector-Emitter Saturation Voltage  
 $V_{CE(sat)} = 2.0 \text{ V (Max.) @ } I_C = 5.0 \text{ A}$
- \* Monolithic Construction with Built-in Base-Emitter Shunt Resistor

|               |               |
|---------------|---------------|
| <b>NPN</b>    | <b>PNP</b>    |
| <b>TIP140</b> | <b>TIP145</b> |
| <b>TIP141</b> | <b>TIP146</b> |
| <b>TIP142</b> | <b>TIP147</b> |

**10 AMPERE DARLINGTON COMPLEMENTARY SILICON POWER TRANSISTORS**  
**60-100 VOLTS**  
**125 WATTS**



**PIN 1.BASE**  
**2.COLLECTOR**  
**3.EMITTER**

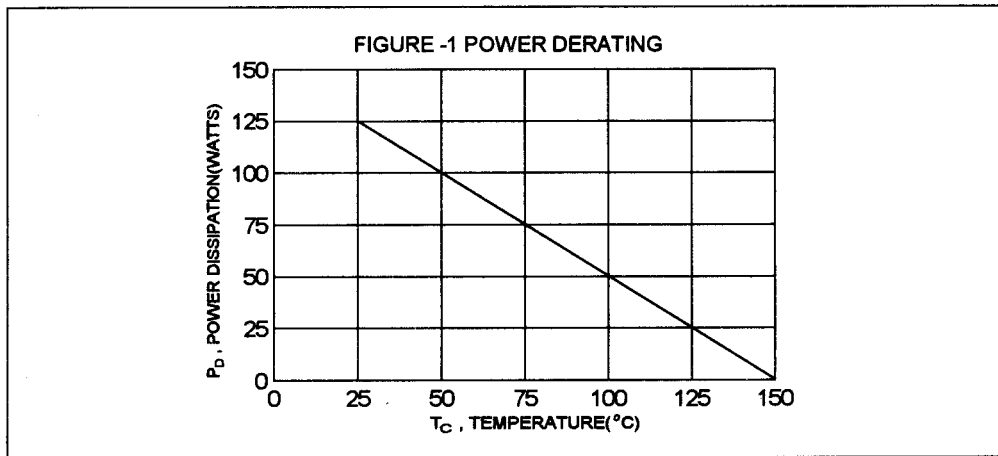
| DIM | MILLIMETERS |       |
|-----|-------------|-------|
|     | MIN         | MAX   |
| A   | 20.63       | 22.38 |
| B   | 15.38       | 16.20 |
| C   | 1.90        | 2.70  |
| D   | 5.10        | 6.10  |
| E   | 14.81       | 15.22 |
| F   | 11.72       | 12.84 |
| G   | 4.20        | 4.50  |
| H   | 1.82        | 2.46  |
| I   | 2.92        | 3.23  |
| J   | 0.89        | 1.53  |
| K   | 5.26        | 5.66  |
| L   | 18.50       | 21.50 |
| M   | 4.68        | 5.36  |
| N   | 2.40        | 2.80  |
| O   | 3.25        | 3.65  |
| P   | 0.55        | 0.70  |

### MAXIMUM RATINGS

| Characteristic  | Symbol            | TIP140<br>TIP145 | TIP141<br>TIP146 | TIP142<br>TIP147 | Unit                     |
|---|-------------------|------------------|------------------|------------------|--------------------------|
| Collector-Emitter Voltage   | $V_{CEO}$         | 60               | 80               | 100              | V                        |
| Collector-Base Voltage  | $V_{CBO}$         | 60               | 80               | 100              | V                        |
| Emitter-Base Voltage  | $V_{EBO}$         | 5.0              |                  |                  | V                        |
| Collector Current-Continuous<br>-Peak   | $I_C$<br>$I_{CM}$ | 10<br>15         |                  |                  | A                        |
| Base Current  | $I_B$             | 0.5              |                  |                  | A                        |
| Total Power Dissipation @ $T_C = 25^\circ\text{C}$<br>Derate above $25^\circ\text{C}$ | $P_D$             | 125<br>1.0       |                  |                  | W<br>W/ $^\circ\text{C}$ |
| Operating and Storage Junction<br>Temperature Range                                   | $T_J, T_{STG}$    | - 65 to +150     |                  |                  | $^\circ\text{C}$         |

### THERMAL CHARACTERISTICS

| Characteristic                      | Symbol          | Max | Unit               |
|-------------------------------------|-----------------|-----|--------------------|
| Thermal Resistance Junction to Case | $R_{\theta jc}$ | 1.0 | $^\circ\text{C/W}$ |



TIP140, TIP141, TIP142 NPN / TIP145, TIP146, TIP147 PNP

**ELECTRICAL CHARACTERISTICS** (  $T_c = 25^\circ\text{C}$  unless otherwise noted )

| Characteristic | Symbol | Min | Max | Unit |
|----------------|--------|-----|-----|------|
|----------------|--------|-----|-----|------|

**OFF CHARACTERISTICS**

|   |  |               |                   |    |
|---|--|---------------|-------------------|----|
| Collector - Emitter Sustaining Voltage (1)<br>( $I_C = 30\text{ mA}$ , $I_B = 0$ )  | TIP140, TIP145<br>TIP141, TIP146<br>TIP142, TIP147 | $V_{CE(sus)}$ | 60<br>80<br>100   | V  |
| Collector Cutoff Current<br>( $V_{CE} = 30\text{ V}$ , $I_B = 0$ )<br>( $V_{CE} = 40\text{ V}$ , $I_B = 0$ )<br>( $V_{CE} = 50\text{ V}$ , $I_B = 0$ )  | TIP140, TIP145<br>TIP141, TIP146<br>TIP142, TIP147 | $I_{CEO}$     | 2.0<br>2.0<br>2.0 | mA |
| Collector Cutoff Current<br>( $V_{CB} = 60\text{ V}$ , $I_E = 0$ )<br>( $V_{CB} = 80\text{ V}$ , $I_E = 0$ )<br>( $V_{CB} = 100\text{ V}$ , $I_E = 0$ ) | TIP140, TIP145<br>TIP141, TIP146<br>TIP142, TIP147 | $I_{CBO}$     | 1.0<br>1.0<br>1.0 | mA |
| Emitter Cutoff Current<br>( $V_{EB} = 5.0\text{ V}$ , $I_C = 0$ )   |  | $I_{EBO}$     | 2.0               | mA |

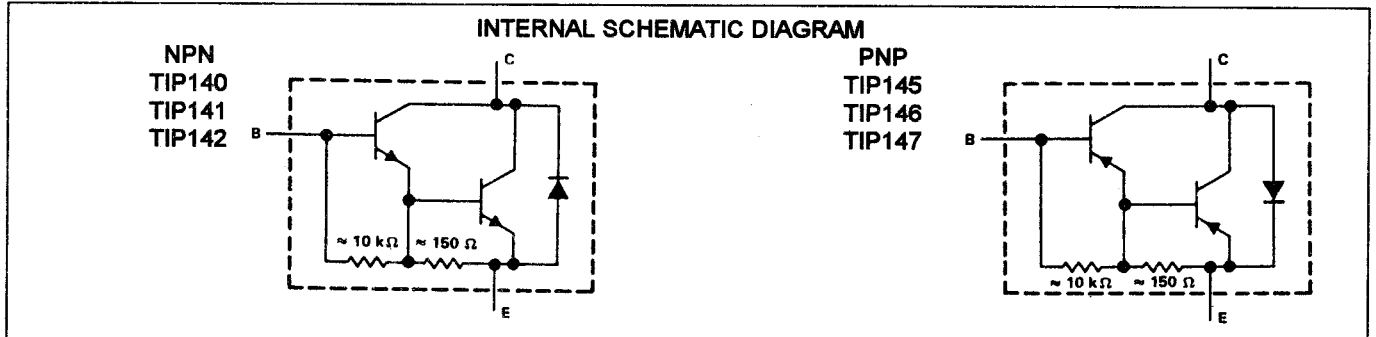
**ON CHARACTERISTICS (1)**

|   |  |               |             |   |
|---|--|---------------|-------------|---|
| DC Current Gain<br>( $I_C = 5.0\text{ A}$ , $V_{CE} = 4.0\text{ V}$ )<br>( $I_C = 10\text{ A}$ , $V_{CE} = 4.0\text{ V}$ )                |  | hFE           | 1000<br>500 |   |
| Collector-Emitter Saturation Voltage<br>( $I_C = 5.0\text{ A}$ , $I_B = 10\text{ mA}$ )<br>( $I_C = 10\text{ A}$ , $I_B = 40\text{ mA}$ ) |  | $V_{CE(sat)}$ | 2.0<br>3.0  | V |
| Base-Emitter Saturation Voltage<br>( $I_C = 10\text{ A}$ , $I_B = 40\text{ mA}$ )   |  | $V_{BE(sat)}$ | 3.5         | V |
| Base-Emitter On Voltage<br>( $I_C = 10\text{ A}$ , $V_{CE} = 4.0\text{ V}$ )  |  | $V_{BE(on)}$  | 3.0         | V |

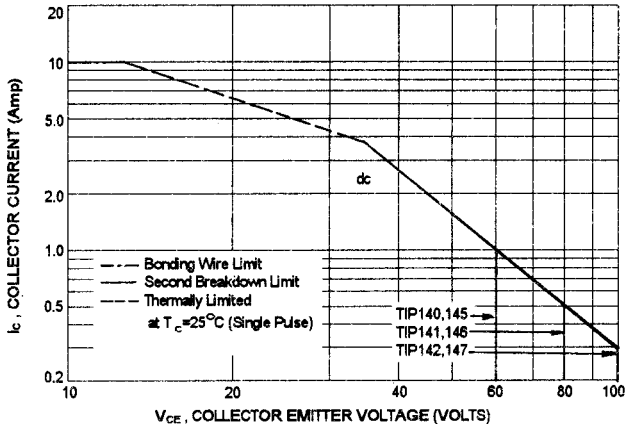
**SWITCHING CHARACTERISTICS**

|              |   |       |           |    |
|--------------|---|-------|-----------|----|
| Delay Time   | $V_{CC} = 30\text{ V}$ , $I_C = 5.0\text{ A}$<br>$I_{B1} = -I_{B2} = 20\text{ mA}$ ,<br>$t_p = 20\mu\text{s}$ , Duty Cycle $\leq 2.0\%$ | $t_d$ | 0.15(Typ) | us |
| Rise Time    |   | $t_r$ | 0.55(Typ) | us |
| Storage Time |   | $t_s$ | 2.5(Typ)  | us |
| Fall Time    |   | $t_f$ | 2.5(Typ)  | us |

(1) Pulse Test: Pulse width = 300 us , Duty Cycle  $\leq 2.0\%$



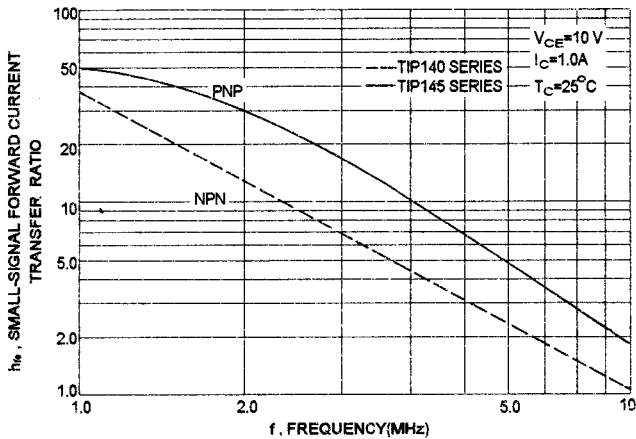
ACTIVE REGION SAFE OPERATING AREA (SOA)



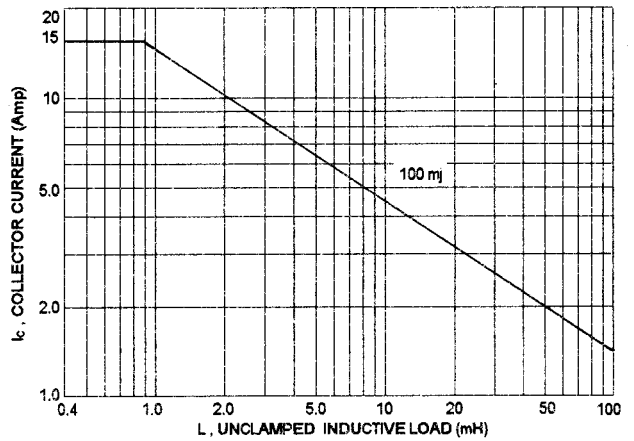
There are two limitation on the power handling ability of a transistor: average junction temperature and second breakdown safe operating area curves indicate  $I_C$ - $V_{CE}$  limits of the transistor that must be observed for reliable operation i.e., the transistor must not be subjected to greater dissipation than curves indicate.

The data of SOA curve is base on  $T_{J(PK)} = 150^\circ\text{C}$ ;  $T_c$  is variable depending on conditions. At high case temperatures, thermal limitation will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

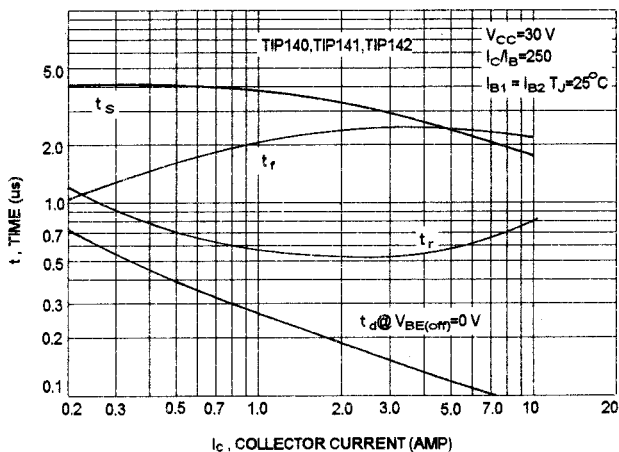
SMALL-SIGNAL COMMON-EMITTER FORWARD CURRENT TRANSFER RATIO



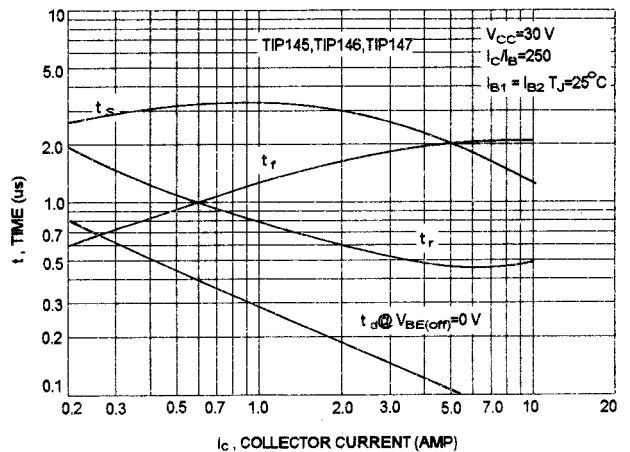
UNCLAMPED INDUCTIVE LOAD



SWITCHING TIME

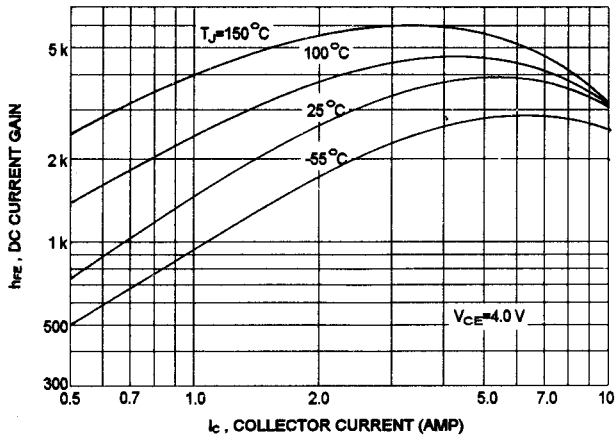


SWITCHING TIME

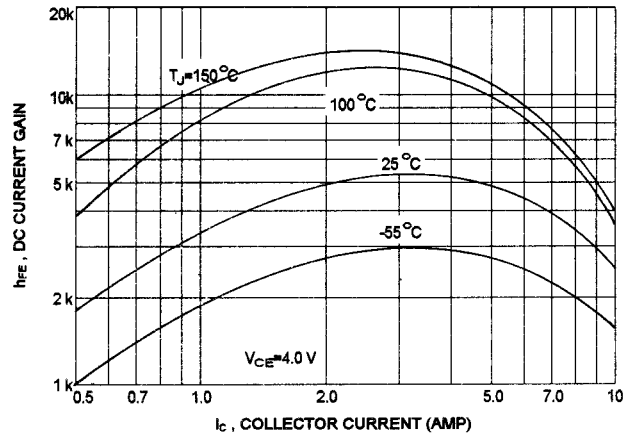


TIP140, TIP141, TIP142 NPN / TIP145, TIP146, TIP147 PNP

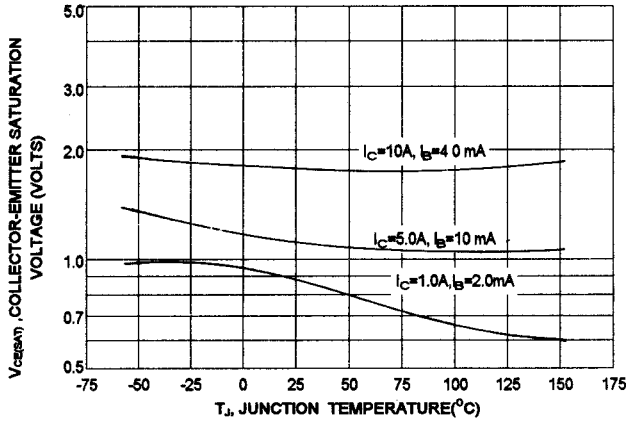
NPN TIP140, TIP141, TIP142  
DC CURRENT GAIN



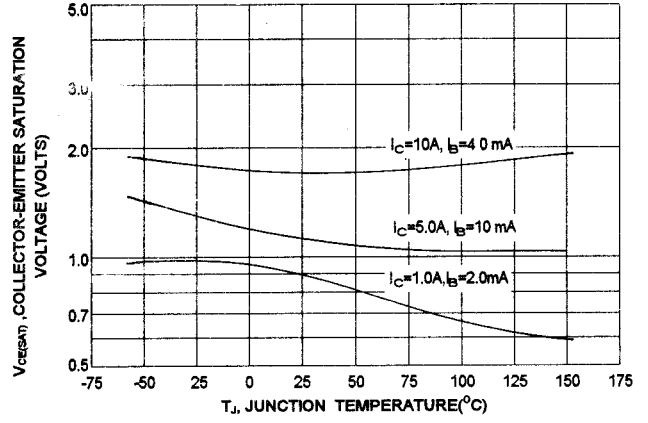
PNP TIP145, TIP146, TIP147  
DC CURRENT GAIN



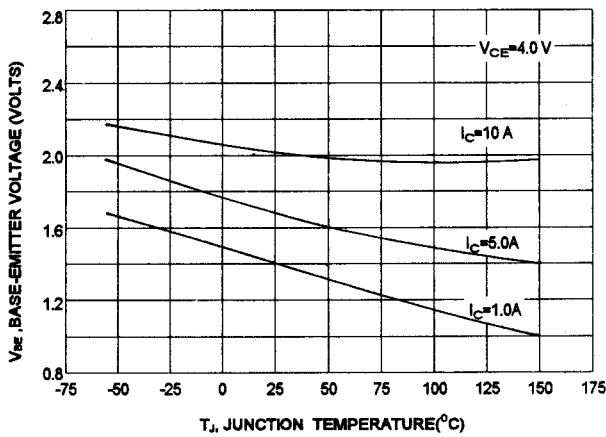
COLLECTOR-EMITTER SATURATION VOLTAGE



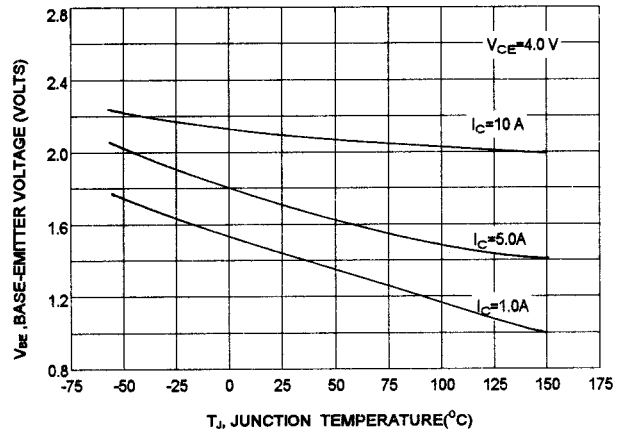
COLLECTOR-EMITTER SATURATION VOLTAGE



BASE-EMITTER VOLTAGE



BASE-EMITTER VOLTAGE



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